

CMOS Digital Integrated Circuits Silicon Monolithic

## TC7SH125F

#### 1. Functional Description

· Bus Buffer with 3-State Output

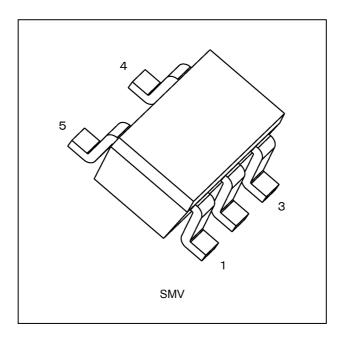
### 2. Features

- (1) AEC-Q100 (Rev. H) (Note 1)
- (2) Wide operating temperature range:  $T_{opr} = -40$  to 125 °C (Note 2)
- (3) High speed operation:  $t_{pd} = 3.8 \text{ ns (typ.)}$  ( $V_{CC} = 5.0 \text{ V}$ ,  $C_L = 15 \text{ pF}$ )
- (4) Low power dissipation:  $I_{CC} = 2.0 \mu A \text{ (max) (} T_a = 25 \text{ °C)}$
- (5) High noise immunity:  $V_{NIH} = V_{NIL} = 28 \% V_{CC}$  (min)
- (6) 5.5 V tolerant inputs
- (7) Wide operating voltage range:  $V_{CC} = 2.0$  to 5.5 V

Note 1: This device is compliant with the reliability requirements of AEC-Q100. For details, contact your Toshiba sales representative.

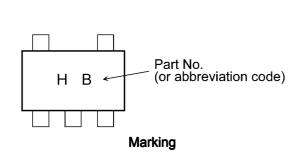
Note 2: For devices with the ordering part number ending in J(CT.  $T_{opr}$  = -40 to 85 °C for the other devices.

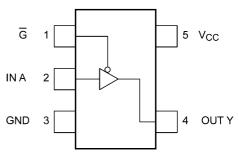
#### 3. Packaging





#### 4. Marking and Pin Assignment





Pin Assignment (Top view)

#### 5. IEC Logic Symbol



#### 6. Truth Table

| G | А | Y |
|---|---|---|
| Н | X | Z |
| L | L | L |
| L | Н | Н |

X: Don't care

Z: High impedance

## 7. Absolute Maximum Ratings (Note) (Unless otherwise specified, Ta = 25 °C)

| Characteristics                 | Symbol           | Note     | Rating                        | Unit |
|---------------------------------|------------------|----------|-------------------------------|------|
| Supply voltage                  | $V_{CC}$         |          | -0.5 to 7.0                   | V    |
| Input voltage                   | V <sub>IN</sub>  |          | -0.5 to 7.0                   |      |
| DC output voltage               | V <sub>OUT</sub> |          | -0.5 to V <sub>CC</sub> + 0.5 |      |
| Input diode current             | I <sub>IK</sub>  |          | -20                           | mA   |
| Output diode current            | I <sub>OK</sub>  | (Note 1) | ±20                           |      |
| DC output current               | l <sub>out</sub> |          | ±25                           |      |
| V <sub>CC</sub> /ground current | I <sub>CC</sub>  |          | ±50                           |      |
| Power dissipation               | P <sub>D</sub>   |          | 200                           | mW   |
| Storage temperature             | T <sub>stg</sub> |          | -65 to 150                    | °C   |

Note: Exceeding any of the absolute maximum ratings, even briefly, lead to deterioration in IC performance or even destruction.

Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings and the operating ranges.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Note 1:  $V_{OUT} < GND$ ,  $V_{OUT} > V_{CC}$ 



## 8. Operating Ranges (Note)

| Characteristics          | Symbol           | Note     | Test Condition                   | Rating               | Unit |
|--------------------------|------------------|----------|----------------------------------|----------------------|------|
| Supply voltage           | V <sub>CC</sub>  |          | _                                | 2.0 to 5.5           | V    |
| Input voltage            | V <sub>IN</sub>  |          | _                                | 0 to 5.5             |      |
| Output voltage           | V <sub>OUT</sub> |          | _                                | 0 to V <sub>CC</sub> |      |
| Operating temperature    | T <sub>opr</sub> | (Note 1) | _                                | -40 to 125           | ů    |
|                          |                  | (Note 2) | _                                | -40 to 85            |      |
| Input rise and fall time | dt/dv            |          | $V_{CC} = 3.3 \pm 0.3 \text{ V}$ | 0 to 100             | ns/V |
|                          |                  |          | $V_{CC} = 5.0 \pm 0.5 \text{ V}$ | 0 to 20              |      |

Note: The operating ranges must be maintained to ensure the normal operation of the device.

Unused inputs must be tied to either  $V_{CC}$  or GND.

Note 1: For devices with the ordering part number ending in J(CT.

Note 2: For devices except those with the ordering part number ending in J(CT.

#### 9. Electrical Characteristics

## 9.1. DC Characteristics (Unless otherwise specified, T<sub>a</sub> = 25 °C)

| Characteristics                          | Symbol          | Test Condition  |                          | V <sub>CC</sub> (V) | Min                   | Тур. | Max                 | Unit |
|--|-----------------|---|--------------------------|---------------------|-----------------------|------|---------------------|------|
| High-level input voltage                 | V <sub>IH</sub> | _   |                          | 2.0                 | 1.5                   | _    | _                   | V    |
|  |                 |   |                          | 3.0 to 5.5          | V <sub>CC</sub> × 0.7 | _    | _                   |      |
| Low-level input voltage                  | V <sub>IL</sub> | _   |                          | 2.0                 | _                     |      | 0.5                 | V    |
|  |                 |   |                          | 3.0 to 5.5          | _                     | _    | $V_{CC} \times 0.3$ |      |
| High-level output voltage                | V <sub>OH</sub> | V <sub>IN</sub> = V <sub>IH</sub> or V <sub>IL</sub>                      | I <sub>OH</sub> = -50 μA | 2.0                 | 1.9                   | 2.0  | _                   | ٧    |
|  |                 |   |                          | 3.0                 | 2.9                   | 3.0  | _                   |      |
|  |                 |   |                          | 4.5                 | 4.4                   | 4.5  | _                   |      |
|  |                 |   | $I_{OH}$ = -4 mA         | 3.0                 | 2.58                  |      | _                   |      |
|  |                 |   | $I_{OH}$ = -8 mA         | 4.5                 | 3.94                  |      | _                   |      |
| Low-level output voltage                 | V <sub>OL</sub> | $V_{IN} = V_{IL}$   | I <sub>OL</sub> = 50 μA  | 2.0                 | _                     | 0.0  | 0.1                 | ٧    |
|  |                 |   |                          | 3.0                 | _                     | 0.0  | 0.1                 |      |
|  |                 |   |                          | 4.5                 | _                     | 0.0  | 0.1                 |      |
|  |                 |   | $I_{OL}$ = 4 mA          | 3.0                 | _                     |      | 0.36                |      |
|  |                 |   | $I_{OL}$ = 8 mA          | 4.5                 | _                     |      | 0.36                |      |
| 3-state output OFF-state leakage current | I <sub>OZ</sub> | $V_{IN} = V_{IH} \text{ or } V_{IL}$<br>$V_{OUT} = V_{CC} \text{ or GND}$ |                          | 5.5                 |                       |      | ±0.25               | μА   |
| Input leakage current                    | I <sub>IN</sub> | V <sub>IN</sub> = 5.5 V or GND  |                          | 0 to 5.5            |                       |      | ±0.1                | μА   |
| Quiescent supply current                 | I <sub>CC</sub> | $V_{IN} = V_{CC}$ or GND  |                          | 5.5                 | _                     | _    | 2.0                 | μА   |



## 9.2. DC Characteristics (Unless otherwise specified, T<sub>a</sub> = -40 to 85 °C)

| Characteristics                          | Symbol          | Test Condition  | V <sub>CC</sub> (V)      | Min        | Max                 | Unit                |    |
|--|-----------------|---|--------------------------|------------|---------------------|---------------------|----|
| High-level input voltage                 | V <sub>IH</sub> | _   |                          | 2.0        | 1.5                 | _                   | V  |
|  |                 |   |                          | 3.0 to 5.5 | $V_{CC} \times 0.7$ | _                   |    |
| Low-level input voltage                  | V <sub>IL</sub> | _   |                          | 2.0        | _                   | 0.5                 | V  |
|  |                 |   |                          | 3.0 to 5.5 | _                   | $V_{CC} \times 0.3$ |    |
| High-level output voltage                | V <sub>OH</sub> | V <sub>IN</sub> = V <sub>IH</sub> or V <sub>IL</sub>                      | I <sub>OH</sub> = -50 μA | 2.0        | 1.9                 | _                   | ٧  |
|  |                 |   |                          | 3.0        | 2.9                 | _                   |    |
|  |                 |   |                          | 4.5        | 4.4                 | _                   |    |
|  |                 |   | $I_{OH} = -4 \text{ mA}$ | 3.0        | 2.48                | _                   |    |
|  |                 |   | $I_{OH}$ = -8 mA         | 4.5        | 3.80                | _                   |    |
| Low-level output voltage                 | V <sub>OL</sub> | $V_{IN} = V_{IL}$   | I <sub>OL</sub> = 50 μA  | 2.0        |                     | 0.1                 | V  |
|  |                 |   |                          | 3.0        | _                   | 0.1                 |    |
|  |                 |   |                          | 4.5        | _                   | 0.1                 |    |
|  |                 |   | $I_{OL} = 4 \text{ mA}$  | 3.0        | _                   | 0.44                |    |
|  |                 |   | $I_{OL}$ = 8 mA          | 4.5        | _                   | 0.44                |    |
| 3-state output OFF-state leakage current | l <sub>OZ</sub> | $V_{IN} = V_{IH} \text{ or } V_{IL}$<br>$V_{OUT} = V_{CC} \text{ or GND}$ |                          | 5.5        | _                   | ±2.5                | μА |
| Input leakage current                    | I <sub>IN</sub> | V <sub>IN</sub> = 5.5 V or GND  |                          | 0 to 5.5   | _                   | ±1.0                | μΑ |
| Quiescent supply current                 | Icc             | V <sub>IN</sub> = V <sub>CC</sub> or GND                                  |                          | 5.5        |                     | 20.0                | μА |

## 9.3. DC Characteristics (Note) (Unless otherwise specified, T<sub>a</sub> = -40 to 125 °C)

| Characteristics                          | Symbol          | Test Condition  | on                       | V <sub>CC</sub> (V) | Min                 | Max                 | Unit |
|--|-----------------|---|--------------------------|---------------------|---------------------|---------------------|------|
| High-level input voltage                 | V <sub>IH</sub> | _   |                          | 2.0                 | 1.5                 | _                   | V    |
|  |                 |   |                          | 3.0 to 5.5          | $V_{CC} \times 0.7$ | _                   |      |
| Low-level input voltage                  | V <sub>IL</sub> | _   |                          | 2.0                 |                     | 0.5                 | V    |
|  |                 |   |                          | 3.0 to 5.5          | _                   | $V_{CC} \times 0.3$ |      |
| High-level output voltage                | V <sub>OH</sub> | V <sub>IN</sub> = V <sub>IH</sub> or V <sub>IL</sub>                      | I <sub>OH</sub> = -50 μA | 2.0                 | 1.9                 | _                   | V    |
|  |                 |   |                          | 3.0                 | 2.9                 | _                   |      |
|  |                 |   |                          | 4.5                 | 4.4                 | _                   |      |
|  |                 |   | $I_{OH}$ = -4 mA         | 3.0                 | 2.40                | _                   |      |
|  |                 |   | I <sub>OH</sub> = -8 mA  | 4.5                 | 3.70                | _                   |      |
| Low-level output voltage                 | V <sub>OL</sub> | $V_{IN} = V_{IL}$   | I <sub>OL</sub> = 50 μA  | 2.0                 | _                   | 0.1                 | V    |
|  |                 |   |                          | 3.0                 | _                   | 0.1                 |      |
|  |                 |   |                          | 4.5                 | _                   | 0.1                 |      |
|  |                 |   | I <sub>OL</sub> = 4 mA   | 3.0                 | _                   | 0.55                |      |
|  |                 |   | I <sub>OL</sub> = 8 mA   | 4.5                 | _                   | 0.55                |      |
| 3-state output OFF-state leakage current | l <sub>OZ</sub> | $V_{IN} = V_{IH} \text{ or } V_{IL}$<br>$V_{OUT} = V_{CC} \text{ or GND}$ |                          | 5.5                 | _                   | ±10.0               | μА   |
| Input leakage current                    | I <sub>IN</sub> | V <sub>IN</sub> = 5.5 V or GND  |                          | 0 to 5.5            |                     | ±2.0                | μΑ   |
| Quiescent supply current                 | I <sub>CC</sub> | V <sub>IN</sub> = V <sub>CC</sub> or GND                                  |                          | 5.5                 | _                   | 40.0                | μΑ   |

Note: For devices with the ordering part number ending in J(CT.



## 9.4. AC Characteristics (Unless otherwise specified, $T_a = 25$ °C, Input: $t_r = t_f = 3$ ns)

| Characteristics               | Symbol                             | Note     | Test<br>Condition | V <sub>CC</sub> (V) | C <sub>L</sub> (pF) | Min | Тур. | Max  | Unit |
|-------------------------------|------------------------------------|----------|-------------------|---------------------|---------------------|-----|------|------|------|
| Propagation delay time        | t <sub>PLH</sub> ,t <sub>PHL</sub> |          | _                 | $3.3 \pm 0.3$       | 15                  | _   | 5.6  | 8.0  | ns   |
|                               |                                    |          |                   |                     | 50                  | _   | 8.1  | 11.5 |      |
|                               |                                    |          |                   | 5.0 ± 0.5           | 15                  | _   | 3.8  | 5.5  |      |
|                               |                                    |          |                   |                     | 50                  | _   | 5.3  | 7.5  |      |
| 3-state output enable time    | t <sub>PZL</sub> ,t <sub>PZH</sub> |          | _                 | $3.3 \pm 0.3$       | 15                  | _   | 5.4  | 8.0  | ns   |
|                               |                                    |          |                   |                     | 50                  | _   | 7.9  | 11.5 |      |
|                               |                                    |          |                   | 5.0 ± 0.5           | 15                  | _   | 3.6  | 5.1  |      |
|                               |                                    |          |                   |                     | 50                  | _   | 5.1  | 7.1  |      |
| 3-state output disable time   | t <sub>PLZ</sub> ,t <sub>PHZ</sub> |          | _                 | $3.3 \pm 0.3$       | 50                  | _   | 9.5  | 13.2 | ns   |
|                               |                                    |          |                   | 5.0 ± 0.5           | 50                  | _   | 6.1  | 8.8  |      |
| Input capacitance             | C <sub>IN</sub>                    |          | _                 |                     |                     | _   | 4    | 10   | pF   |
| Output capacitance            | C <sub>OUT</sub>                   |          | _                 |                     |                     | _   | 6    | _    | pF   |
| Power dissipation capacitance | C <sub>PD</sub>                    | (Note 1) | _                 |                     |                     | -   | 14   | _    | pF   |

Note 1:  $C_{PD}$  is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load. Average operating current can be obtained by the equation.  $I_{CC(opr)} = C_{PD} \cdot V_{CC} \cdot f_{IN} + I_{CC}$ 

# 9.5. AC Characteristics (Unless otherwise specified, $T_a = -40$ to 85 °C, Input: $t_r = t_f = 3$ ns)

| Characteristics             | Symbol                             | Note | Test Condition | V <sub>CC</sub> (V) | C <sub>L</sub> (pF) | Min | Max  | Unit |
|-----------------------------|------------------------------------|------|----------------|---------------------|---------------------|-----|------|------|
| Propagation delay time      | t <sub>PLH</sub> ,t <sub>PHL</sub> |      | _              | $3.3\pm0.3$         | 15                  | 1.0 | 9.5  | ns   |
|                             |                                    |      |                |                     | 50                  | 1.0 | 13.0 |      |
|                             |                                    |      |                | $5.0 \pm 0.5$       | 15                  | 1.0 | 6.5  |      |
|                             |                                    |      |                |                     | 50                  | 1.0 | 8.5  |      |
| 3-state output enable time  | $t_{PZL}, t_{PZH}$                 |      | _              | $3.3\pm0.3$         | 15                  | 1.0 | 9.5  | ns   |
|                             |                                    |      |                |                     | 50                  | 1.0 | 13.0 |      |
|                             |                                    |      |                | 5.0 ± 0.5           | 15                  | 1.0 | 6.0  |      |
|                             |                                    |      |                |                     | 50                  | 1.0 | 8.0  |      |
| 3-state output disable time | $t_{PLZ}, t_{PHZ}$                 |      | _              | $3.3\pm0.3$         | 50                  | 1.0 | 15.0 | ns   |
|                             |                                    |      |                | 5.0 ± 0.5           | 50                  | 1.0 | 10.0 |      |
| Input capacitance           | C <sub>IN</sub>                    |      | _              |                     |                     | _   | 10   | pF   |

# 9.6. AC Characteristics (Note) (Unless otherwise specified, $T_a$ = -40 to 125 °C, Input: $t_r$ = $t_f$ = 3 ns)

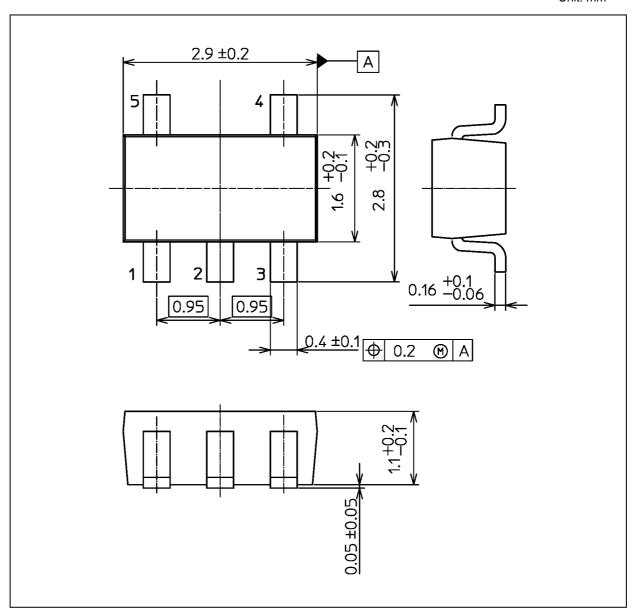
| Characteristics             | Symbol                             | Note | Test Condition | V <sub>CC</sub> (V) | C <sub>L</sub> (pF) | Min | Max  | Unit |
|-----------------------------|------------------------------------|------|----------------|---------------------|---------------------|-----|------|------|
| Propagation delay time      | t <sub>PLH</sub> ,t <sub>PHL</sub> |      | _              | $3.3 \pm 0.3$       | 15                  | 1.0 | 11.0 | ns   |
|                             |                                    |      |                |                     | 50                  | 1.0 | 14.5 |      |
|                             |                                    |      |                | $5.0 \pm 0.5$       | 15                  | 1.0 | 7.5  |      |
|                             |                                    |      |                |                     | 50                  | 1.0 | 9.5  |      |
| 3-state output enable time  | $t_{PZL}, t_{PZH}$                 |      | _              | $3.3 \pm 0.3$       | 15                  | 1.0 | 11.0 | ns   |
|                             |                                    |      |                |                     | 50                  | 1.0 | 14.5 |      |
|                             |                                    |      |                | $5.0 \pm 0.5$       | 15                  | 1.0 | 7.0  |      |
|                             |                                    |      |                |                     | 50                  | 1.0 | 9.0  |      |
| 3-state output disable time | $t_{PLZ}, t_{PHZ}$                 |      | _              | $3.3\pm0.3$         | 50                  | 1.0 | 16.5 | ns   |
|                             |                                    |      |                | 5.0 ± 0.5           | 50                  | 1.0 | 11.0 |      |
| Input capacitance           | C <sub>IN</sub>                    |      | _              |                     | ·                   | _   | 10   | pF   |

Note: For devices with the ordering part number ending in J(CT.



### **Package Dimensions**

Unit: mm



Weight: 14 mg (typ.)

|               | Package Name(s) |
|---------------|-----------------|
| JEDEC: SOT-25 |                 |
| Nickname: SMV |                 |



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